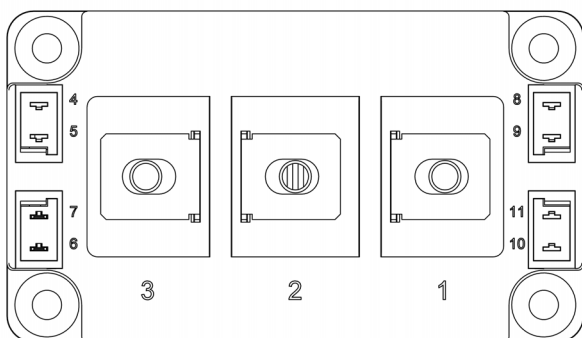
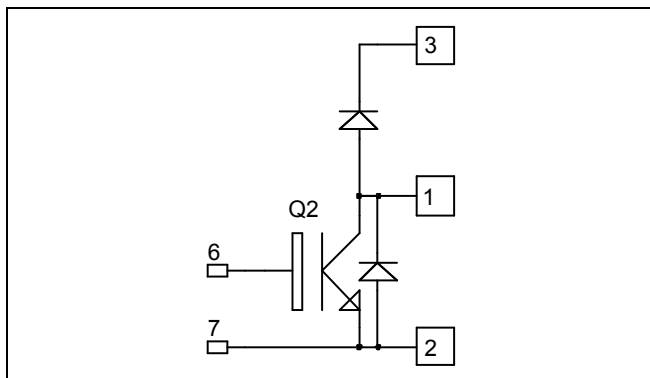


**Boost chopper
Trench + Field Stop IGBT3
Power Module**

**$V_{CES} = 1700V$
 $I_C = 300A @ T_c = 80^\circ C$**



Application

- AC and DC motor control
- Switched Mode Power Supplies
- Power Factor Correction

Features

- Trench + Field Stop IGBT3 Technology
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 20 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- High level of integration
- M6 power connectors

Benefits

- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive T_C of V_{CEsat}
- RoHS Compliant

Absolute maximum ratings

Symbol	Parameter	Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage	1700	V
I_C	Continuous Collector Current	$T_C = 25^\circ C$ 400 $T_C = 80^\circ C$ 300	A
I_{CM}	Pulsed Collector Current	$T_C = 25^\circ C$ 600	
V_{GE}	Gate - Emitter Voltage	± 20	V
P_D	Maximum Power Dissipation	$T_C = 25^\circ C$ 1470	W
RBSOA	Reverse Bias Safe Operating Area	$T_J = 125^\circ C$ 600A@1650V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

All ratings @ $T_j = 25^\circ\text{C}$ unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1700V$			3	mA
$V_{CE(on)}$	Collector Emitter on Voltage	$V_{GE} = 15V$ $I_C = 300A$	$T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$	2.0 2.4	2.5	V
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 12\text{ mA}$	5.2	5.8	6.4	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$			400	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
C_{ies}	Input Capacitance	$V_{GE} = 0V, V_{CE} = 25V$		27		nF
C_{res}	Reverse Transfer Capacitance	$f = 1\text{MHz}$		0.9		nF
Q_G	Gate charge	$V_{GE} = \pm 15V, I_C = 300A$ $V_{CE} = 900V$		3.5		μC
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C) $V_{GE} = \pm 15V$ $V_{Bus} = 900V$ $I_C = 300A$ $R_G = 4.7\Omega$		280		ns
T_r	Rise Time			80		
$T_{d(off)}$	Turn-off Delay Time			850		
T_f	Fall Time			120		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C) $V_{GE} = \pm 15V$ $V_{Bus} = 900V$ $I_C = 300A$ $R_G = 4.7\Omega$		300		ns
T_r	Rise Time			100		
$T_{d(off)}$	Turn-off Delay Time			1000		
T_f	Fall Time			200		
E_{on}	Turn On Energy	$V_{GE} = \pm 15V$ $V_{Bus} = 900V$	$T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$	71 105		mJ
E_{off}	Turn Off Energy	$I_C = 300A$ $R_G = 4.7\Omega$	$T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$	64 94		
I_{sc}	Short Circuit data	$V_{GE} \leq 15V; V_{Bus} = 1000V$ $t_p \leq 10\mu\text{s}; T_j = 125^\circ\text{C}$		1200		A

Reverse diode ratings and characteristics

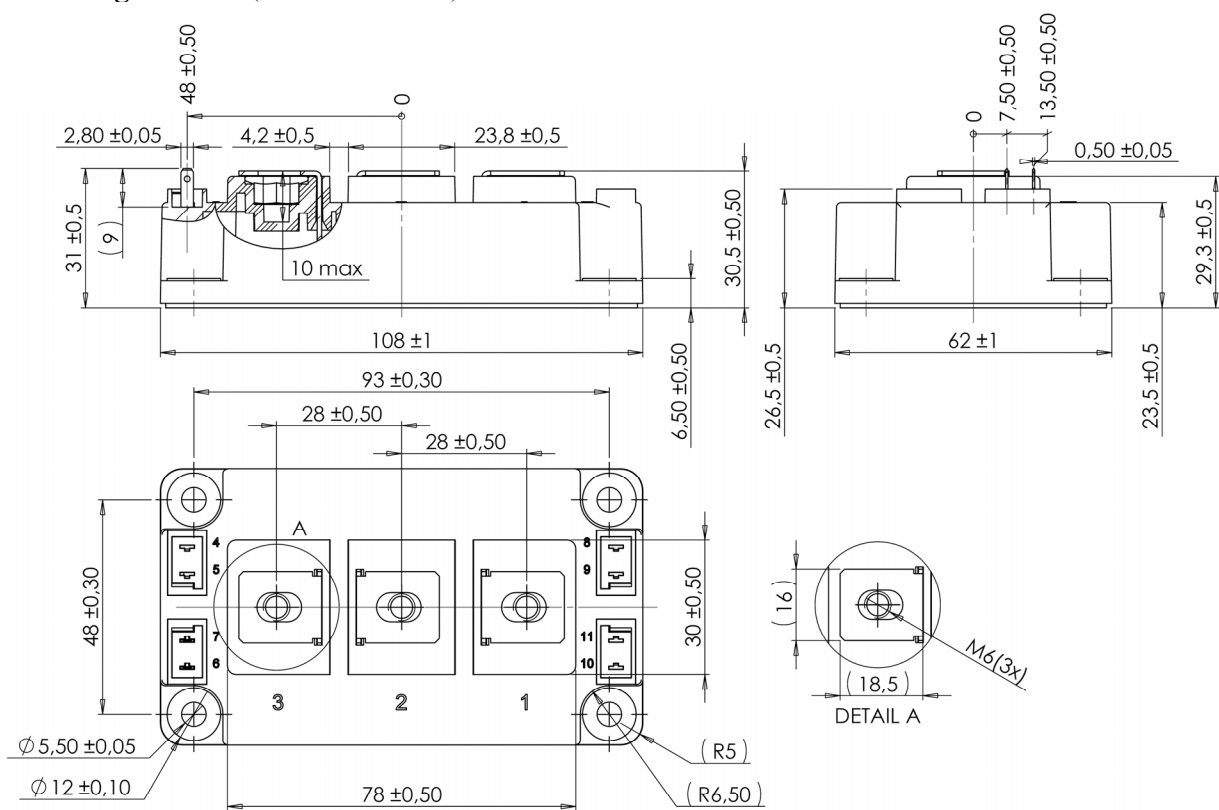
Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage		1700			V
I_{RRM}	Maximum Reverse Leakage Current	$V_R = 1700V$	$T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$		750 1000	μA
I_F	DC Forward Current		$T_c = 80^\circ\text{C}$	300		A
V_F	Diode Forward Voltage	$I_F = 300A$	$T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$	1.8 1.9	2.2	V
t_{rr}	Reverse Recovery Time	$I_F = 300A$ $V_R = 900V$ $di/dt = 3500A/\mu\text{s}$	$T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$	385 490		ns
Q_{rr}	Reverse Recovery Charge		$T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$	76 124		
E_{rr}	Reverse Recovery Energy		$T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$	35 70		mJ



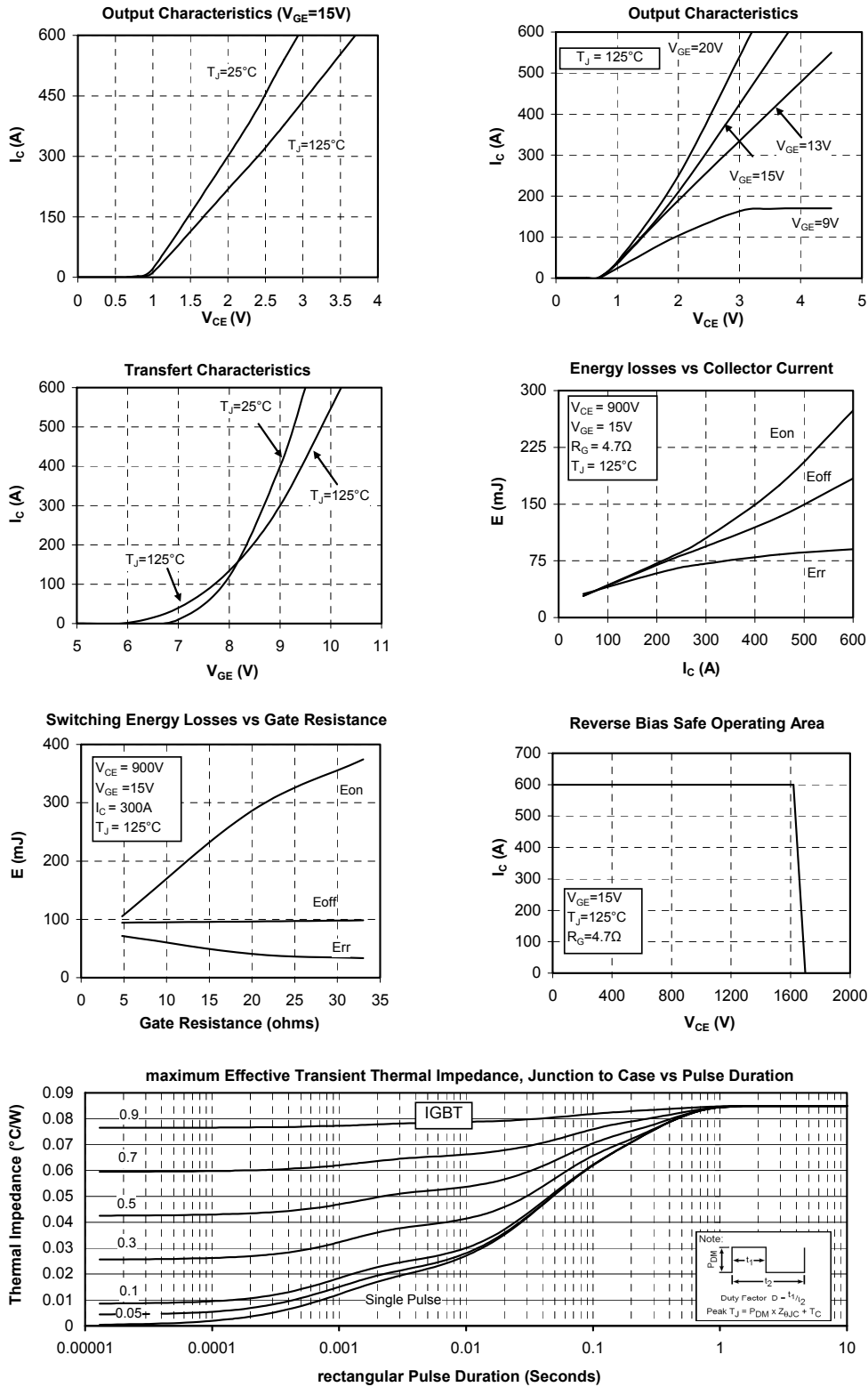
<i>Symbol</i>	<i>Characteristic</i>
α	Angle of attack
β	Angle of sideslip
γ	Angle of yaw
δ	Angle of deflection
ϵ	Angle of elevation
ζ	Angle of depression
η	Angle of incidence
θ	Angle of rotation
ϕ	Angle of roll
ψ	Angle of yaw
χ	Angle of pitch
λ	Angle of attack
μ	Angle of sideslip
ν	Angle of yaw
ξ	Angle of deflection
ω	Angle of elevation
σ	Angle of depression
τ	Angle of incidence
κ	Angle of rotation
ι	Angle of roll
υ	Angle of yaw
ϕ	Angle of pitch
χ	Angle of attack
λ	Angle of sideslip
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ϕ	Angle of yaw
χ	Angle of deflection
λ	Angle of elevation
μ	Angle of depression
ν	Angle of incidence
ξ	Angle of rotation
ω	Angle of roll
σ	Angle of yaw
τ	Angle of pitch
κ	Angle of attack
ι	Angle of sideslip
υ	Angle of yaw
ϕ	Angle of deflection
χ	Angle of elevation
λ	Angle of depression
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ξ	Angle of roll
ω	Angle of yaw
σ	Angle of pitch
τ	Angle of attack
κ	Angle of sideslip
ι	Angle of yaw
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χ	Angle of depression
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ξ	Angle of yaw
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λ	Angle of attack
μ	Angle of sideslip
ν	Angle of yaw
ξ	Angle of deflection
ω	Angle of elevation

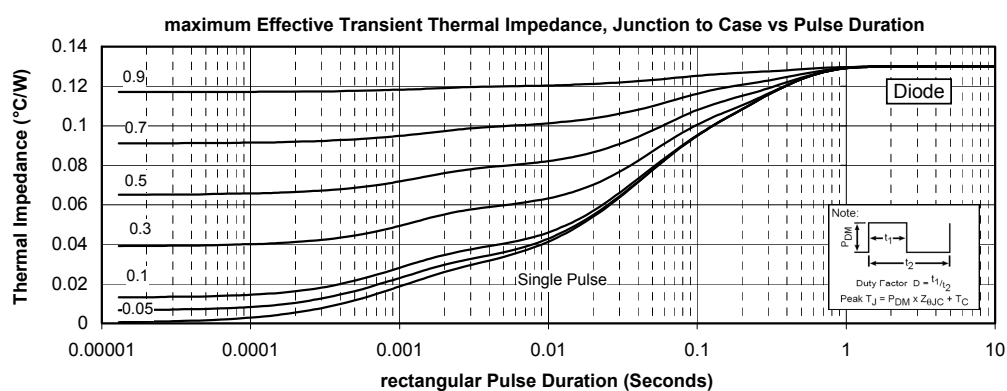
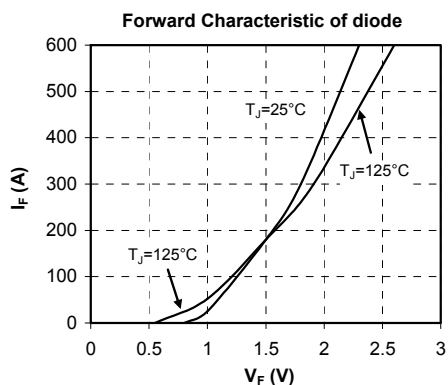
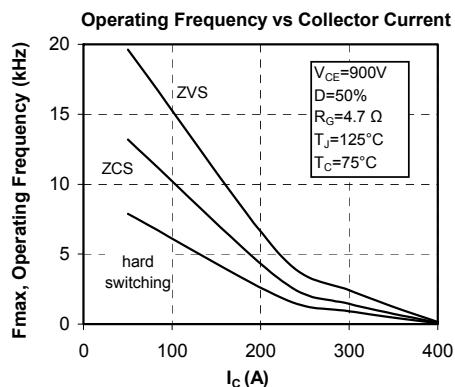
Symbol	Characteristic			Min	Typ	Max	Unit
R _{thJC}	Junction to Case Thermal Resistance			IGBT		0.085	°C/W
				Diode		0.13	
V _{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T _J	Operating junction temperature range			-40		150	°C
T _{STG}	Storage Temperature Range			-40		125	
T _C	Operating Case Temperature			-40		125	
Torque	Mounting torque	For terminals	M6	3		5	N.m
		To Heatsink	M6	3		5	
Wt	Package Weight					350	g

D3 Package outline (dimensions in mm)



Typical Performance Curve





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